



TF252 — N-channel Silicon Junction FET Electret Condenser Microphone Applications

Features

- High gain : $G_V=1.0\text{dB typ}$ ($V_{CC}=2\text{V}$, $R_L=2.2\text{k}\Omega$, $C_{in}=5\text{pF}$, $V_{IN}=10\text{mV}$, $f=1\text{kHz}$)
- Ultrasmall package facilitates miniaturization in end products [1.0mm×0.6mm×0.27mm (max 0.3mm)]
- Best suited for use in Electret Condenser Microphone for audio equipments and telephones
- Excellent voltage characteristics
- Excellent transient characteristics
- Adoption of FBET process
- Halogen free compliance
- Protection diode in

Specifications

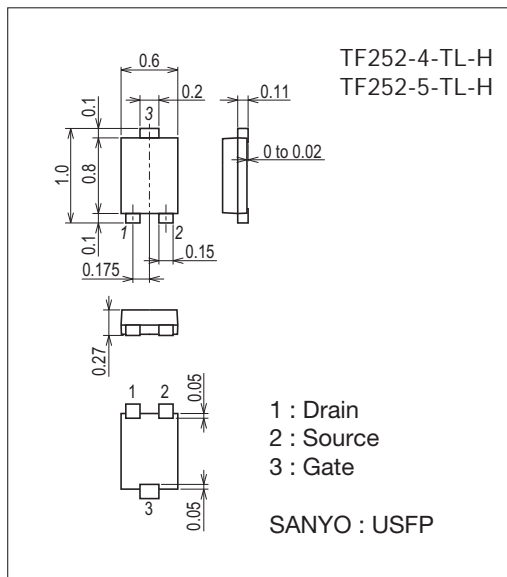
Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V_{GDO}		-20	V
Gate Current	I_G		10	mA
Drain Current	I_D		1	mA
Allowable Power Dissipation	P_D		30	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Package Dimensions

unit : mm (typ)

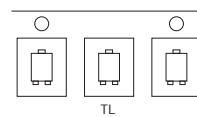
7055-001



Product & Package Information

- Package : USFP
- JEITA, JEDEC : -
- Minimum Packing Quantity : 10,000 pcs./reel

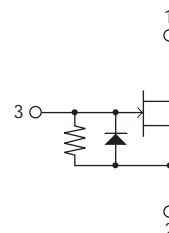
Packing Type: TL



Marking



Electrical Connection



TF252

Electrical Characteristics at Ta=25°C

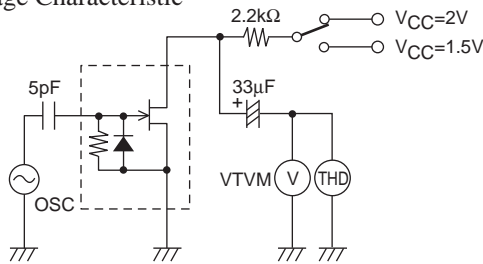
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	V(BR)GDO	I _G =-100μA	-20			V
Cutoff Voltage	V _{GS(off)}	V _{DS} =2V, I _D =1μA	-0.1	-0.4	-1.0	V
Drain Current	I _{DSS}	V _{DS} =2V, V _{GS} =0V	140*		350*	μA
Forward Transfer Admittance	y _{fs}	V _{DS} =2V, V _{GS} =0V, f=1kHz	0.8	1.4		mS
Input Capacitance	C _{iss}	V _{DS} =2V, V _{GS} =0V, f=1MHz		3.1		pF
Reverse Transfer Capacitance	C _{rss}			0.95		pF
[Ta=25°C, V _{CC} =2V, R _L =2.2kΩ, C _{in} =5pF, See specified Test Circuit.]						
Voltage Gain	G _V	V _{IN} =10mV, f=1kHz		1.0		dB
Reduced Voltage Characteristic	ΔG _V	V _{IN} =10mV, f=1kHz, V _{CC} =2.0V → 1.5V		-0.6	-2.0	dB
Frequency Characteristic	ΔG _V f	f=1kHz to 110Hz			-1.0	dB
Total Harmonic Distortion	THD	V _{IN} =30mV, f=1kHz		0.65		%
Output Noise Voltage	V _{NO}	V _{IN} =0V, A curve		-106	-102	dB

* : The TF252 is classified by I_{DSS} as follows : (unit : μA)

Rank	4	5
I _{DSS}	140 to 240	210 to 350

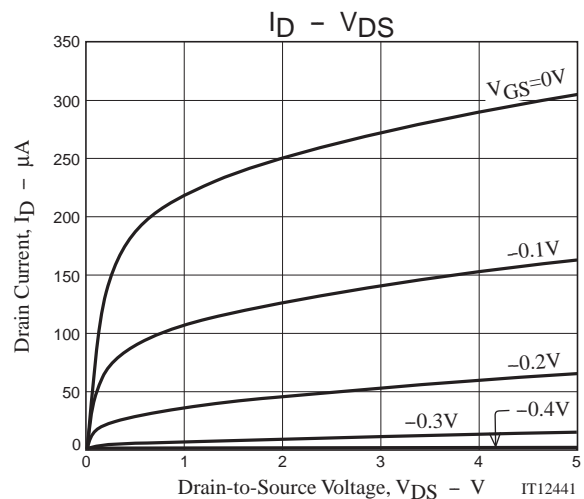
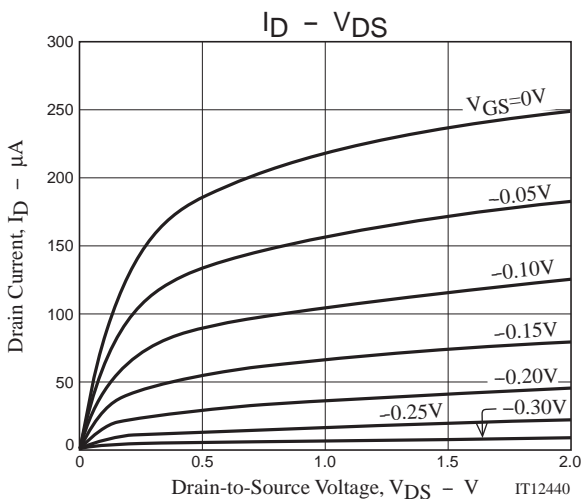
Test Circuit

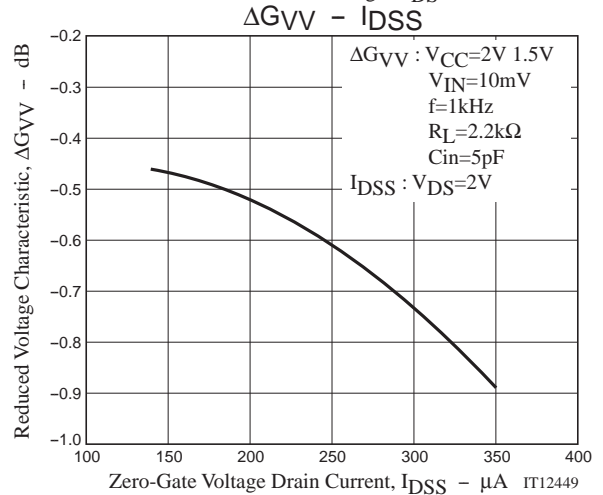
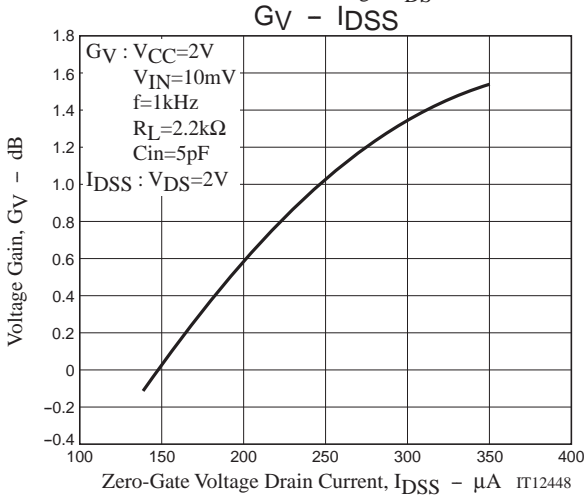
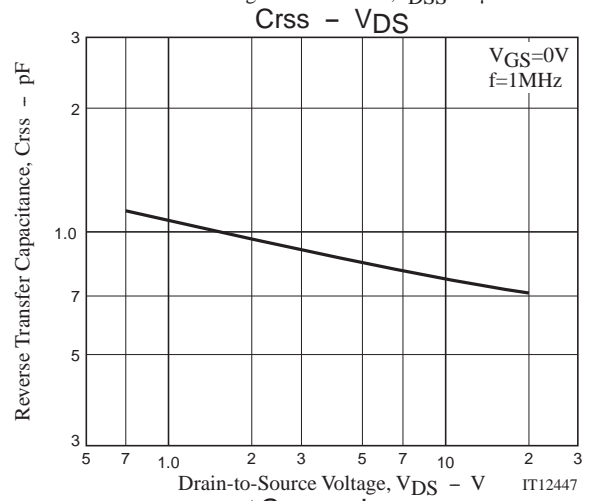
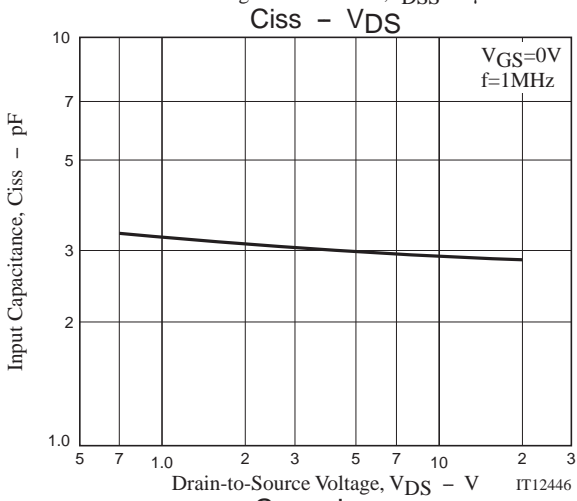
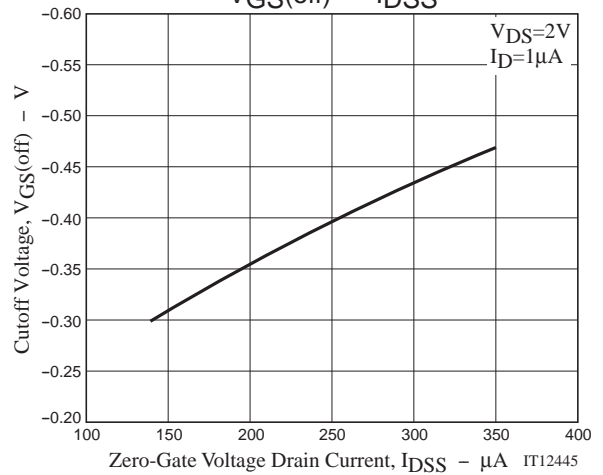
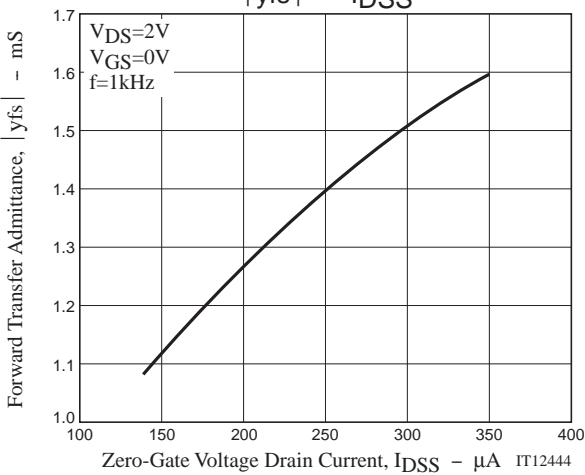
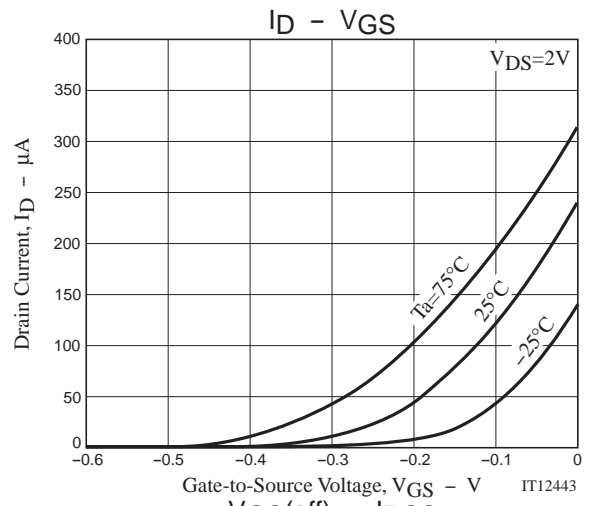
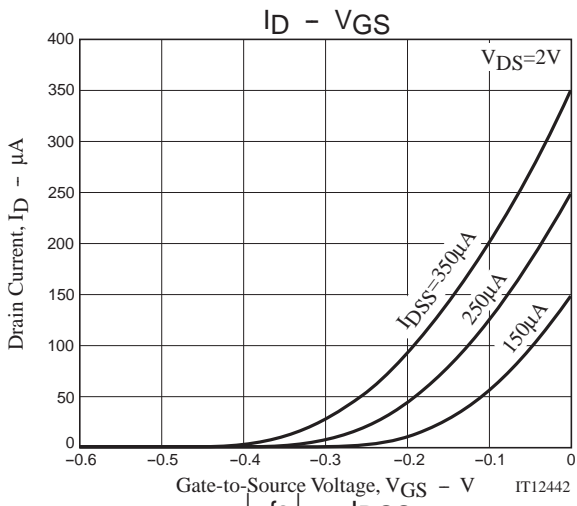
- Voltage gain
- Frequency Characteristic
- Distortion
- Reduced Voltage Characteristic

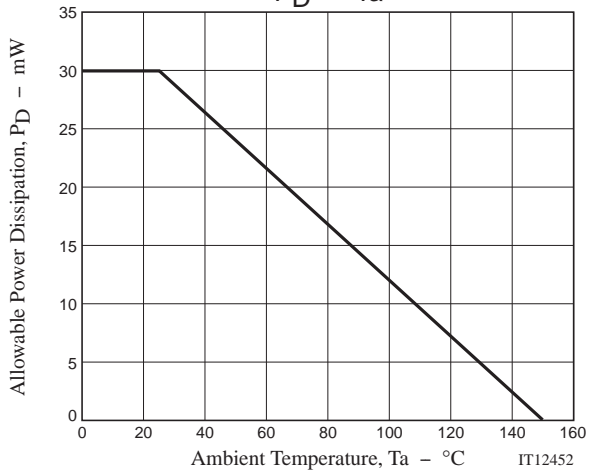
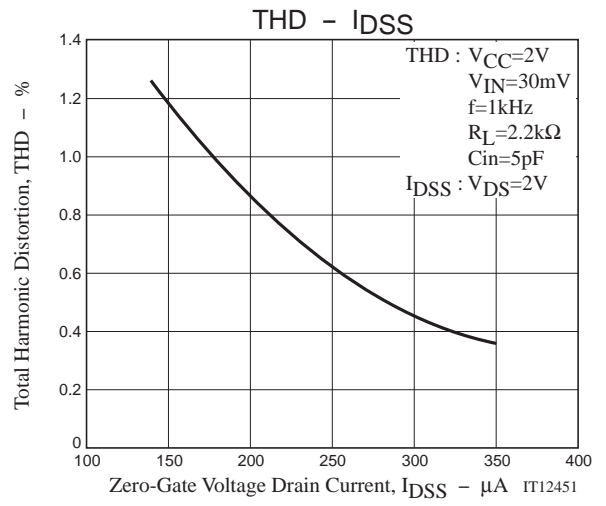
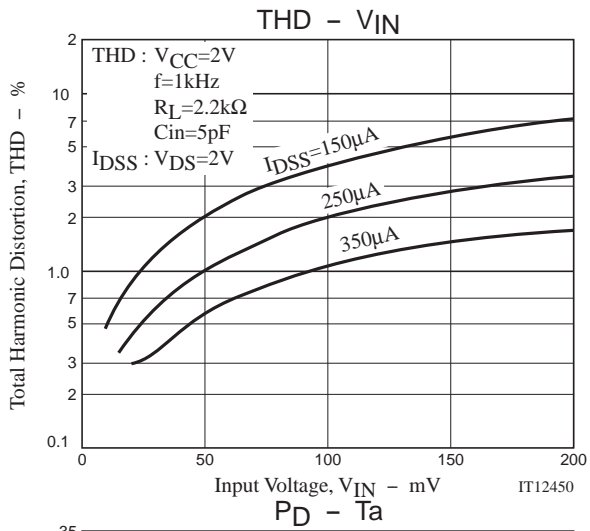


Ordering Information

Device	Package	Shipping	memo
TF252-4-TL-H	USFP	10,000pcs./reel	Pb Free and Halogen Free
TF252-5-TL-H	USFP	10,000pcs./reel	







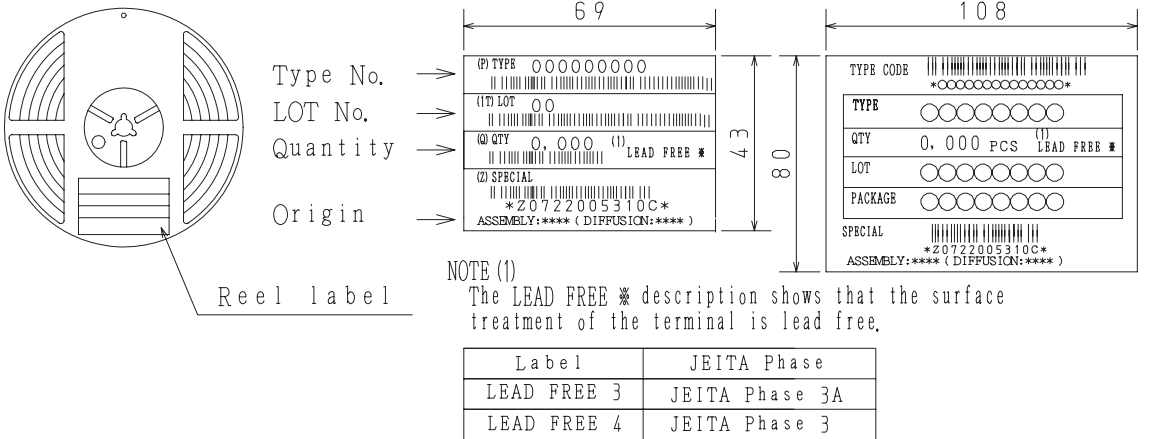
Taping Specification

TF252-4-TL-H, TF252-5-TL-H

1. Packing Format

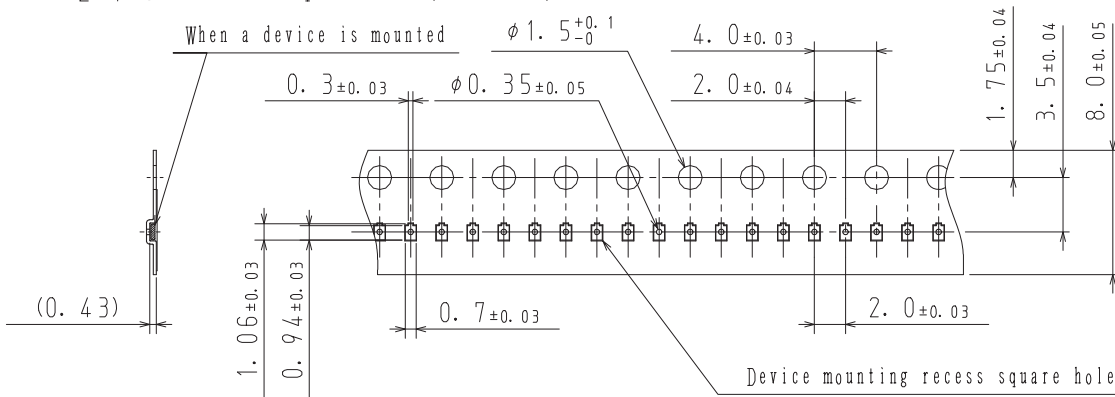
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
USFP	USFP	10,000	50,000	300,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

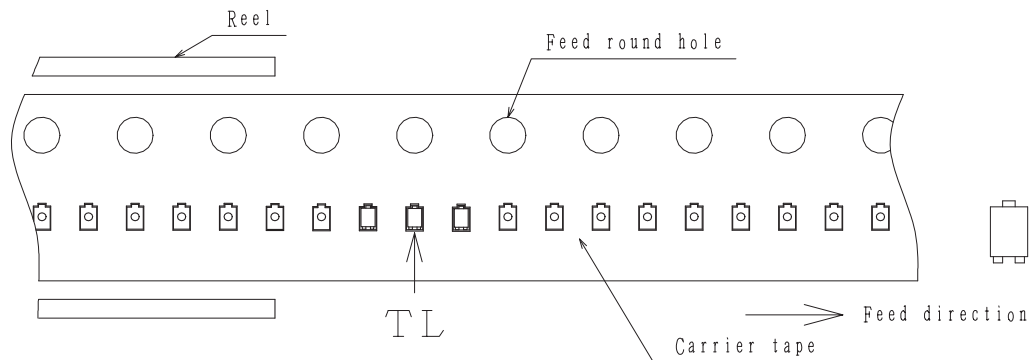


2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with one electrode terminal on the feed hole side.....TL

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